

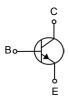
Package Marking and Ordering Information

Features

Collector Current: I_C=0.6A Power Dissipation of 300mW

Product IDPackMarkingQty(PCS)CMPT4401 TR PBFREESOT-232X3000





Maximum Ratings (Ta=25 unless otherwise noted)

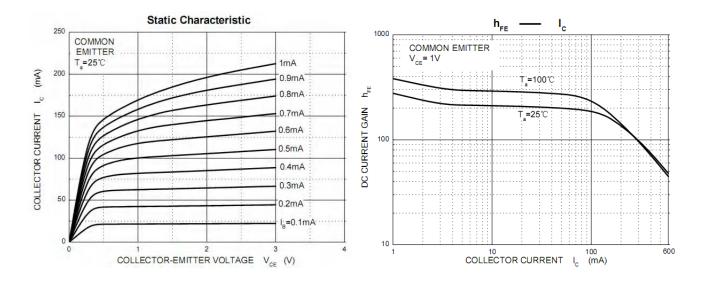
Parameter	Symbol	Limit	Unit	
Collector-Base Voltage	V _{CBO}	60	V	
Collector-Emitter Voltage	V _{CEO}	40	V	
Emitter-Base Voltage	V _{EBO}	6	V	
Collector Current	I _C	600	mA	
Collector Power Dissipation	P _C	300	mW	
Thermal Resistance From Junction To Ambient	R _{OJA}	417	°C/W	
Junction Temperature	T _j	150	℃	
Storage Temperature	T _{stg}	-55∼+150	℃	



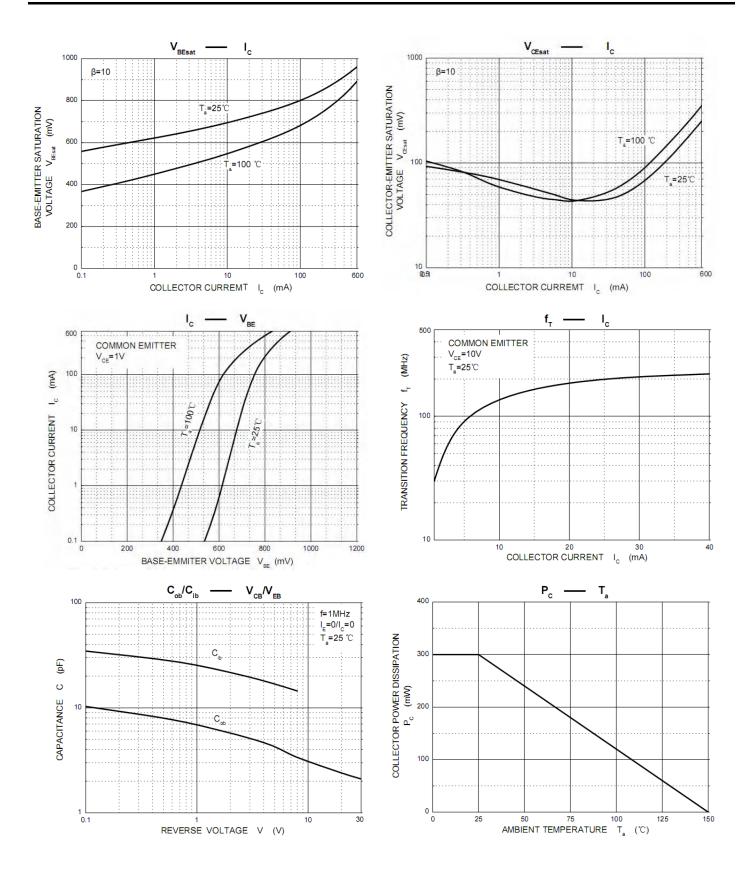
Electrical Characteristics (Ta=25 unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA,I _E =0	60			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =1mA,I _B =0	40			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =100μA , I _C =0	6			V
Collector cut-off current	I _{CBO}	V _{CB} =50V,I _E =0			0.1	μA
Collector cut-off current	I _{CEX}	Vce=35V, Veb=0.4V			0.1	μA
Emitter cut-off current	I _{EBO}	$V_{EB}=5V,I_{C}=0$			0.1	μA
DC current gain	h _{FE1}	V _{CE} =1V, I _C =0.1mA	20			
	h _{FE2}	V _{CE} =1V, I _C =1mA	40			
	h _{FE3}	V _{CE} =1V, I _C =10mA	80			
	h _{FE4}	V _{CE} =1V, I _C =150mA	100		300	
	h _{FE5}	V _{CE} =2V, I _C =500mA	40			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =150mA,I _B =15mA			0.4	V
		I _C =500mA,I _B =50mA			0.75	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C =150mA,I _B =15mA			0.95	V
		I _C =500mA,I _B =50mA			1.2	V
Transition frequency	f _T	V _{CE} =10V, I _C =20mA,f =100MHz	250			MHz
Delay time	t _d	Vcc=30V, VBE(off)=-2V			15	ns
Rise time	t _r	Ic=150mA , Iв1=15mA			20	ns
Storage time	ts	Vcc=30V, Ic=150mA			225	ns
Fall time	t _f	I _{B1} =I _{B2} =15mA			60	ns

Typical Characteristics

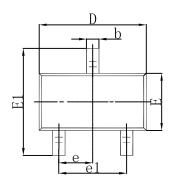


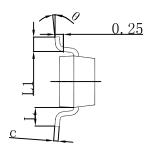
CMPT4401 TR PBFREE NPN Plastic-Encapsulate Transistors

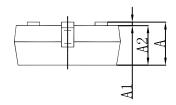




SOT-23 Package Outline Dimensions

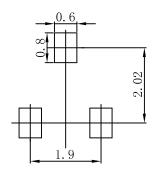






Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
Ĺ	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

CMPT4401 TR PBFREE NPN Plastic-Encapsulate Transistors

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